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AMENDMENTS TO THE CLAIMS:

- 1. (Currently Amended) A liquid crystal display device, comprising:
- a display panel including a lower layer at the lowest portion of the display panel and an uppermost layer, positioned above the lowest layer at the uppermost portion of said display panel;
- a first substrate forming said uppermost layer of said display panel, including:
 - a) a switching element on the first substrate, said switching element being connected to a gate line and a data line, the switching element being a thin film transistor having a gate electrode formed on the first substrate, a gate insulating layer formed on an exposed surface of the first substrate while covering the gate electrode, an active layer on the gate insulating layer over the gate electrode, an ohmic contact layer on the active layer, a source electrode on the ohmic contact layer, a drain electrode on the ohmic contact layer, and a first light absorbing film under the gate electrode;
 - b)a passivation film formed over the whole surface of the first substrate while covering the switching element;
 - c) a pixel electrode on the passivation film;
 - d)a black matrix formed on the passivation film and over the

switching element;

- e) a color filter formed over the pixel electrode; and
- f) a first orientation film formed on the black matrix and the color filter and above the pixel electrode;

a second substrate having no switching element disposed thereon, forming said lowest portion of the display panel, said second substrate being aligned with the first substrate, said second substrate having a common electrode and a second orientation film, said second orientation film being formed on the common electrode;

- a sealant for sealing said first and second substrates;
- a liquid crystal layer interposed between said first and second substrates; and
- a backlight device disposed beneath said second substrate such that said second substrate is located between said backlight device and said first substrate.
- 2. (Currently Amended) The liquid crystal display device of claim 1, wherein the switching element is a thin film transistor, the thin film transistor having a gate electrode formed on the first substrate, a gate insulating layer formed on the exposed surface of the first substrate while covering the gate electrode, a semiconductor layer formed over the gate electrode, a andwherein

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the source electrode overlapping overlaps one end portion of the semiconductor

active layer, and a the drain electrode overlapping overlaps the other end

portion of the semiconductor active layer.

3. (Currently Amended) The liquid crystal display device of claim 2,

further comprising a first light absorbing film formed under the gate electrode,

a second light absorbing film formed under the source electrode, and a third

light absorbing film formed under the drain electrode.

4. (Currently Amended) The liquid crystal display device of claim 2,

further comprising, a first light absorbing film formed under the gate electrode

and a second light absorbing film formed under the semiconductor layer.

5. (Previously Presented) The liquid crystal display device of claim 3,

further comprising, the first light absorbing film formed under the gate line,

and the second light absorbing film formed under data line.

6. (Previously Presented) The liquid crystal display device of claim 4,

further comprising, the first light absorbing film formed under the gate line,

and the second light absorbing film formed under data line.

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7. (Previously Presented) The liquid crystal display device of claim 5,

wherein the back light device is for supplying light to the liquid crystal layer.

8. (Original) The liquid crystal display device of claim 7, wherein the

common electrode and the pixel electrode are made of indium tin oxide (ITO).

9. (Original) The liquid crystal display device of claim 1, wherein the

common electrode is made of an opaque conductive material.

10. (Original) The liquid crystal display device of claim 3, wherein the

common electrode is made of an opaque conductive material.

11. (Original) The liquid crystal display device of claim 4, wherein the

common electrode is made of an opaque conductive material.

12. (Currently Amended) A method of manufacturing a liquid crystal

display device which comprises an array of thin film transistors, an array of

pixel electrodes and a backlight device, said method including:

forming a gate line and a gate electrode on a first substrate said first

substrate forming the uppermost layer of a display panel, the gate electrode

extending from the gate line;

forming a gate insulating layer on the exposed surface of the upper substrate while covering the gate line and the gate electrode;

forming a semiconductor an active layer on the gate insulating layer over the gate electrode;

forming an ohmic contact layer on the active layer;

forming a data line and source and drain electrodes, the source electrode on the ohmic contact layer and overlapping one end portion of the semiconductor active layer, the drain electrode on the ohmic contact layer and overlapping the other end portion of the semiconductor active layer, the source and drain electrodes spaced apart from each other, the source electrode extending from the data line, said gate, source and drain electrodes comprising a thin film transistor formed on said first substrate;

forming a first light absorbing film under the gate electrode;

forming a passivation film over the whole surface of the first substrate while covering the source and drain electrodes, the passivation film having a contact hole on the drain electrode;

forming a pixel electrode on the passivation film, the pixel electrode electrically connected with the drain electrode through the contact hole;

forming a color filter on the pixel electrode;

forming a black matrix over the thin film transistor;

forming a first orientation film on the color filters and the black

matrices;

forming a common electrode on a second substrate;

forming a second orientation film on the common electrode;

aligning the first substrate turned upside down with the second substrate with a gap between the first substrate and the second substrate so that the thin film transistor is also turned upside down and the first orientation film of the first substrate is opposite to the second orientation film of the second substrate;

sealing the first and second substrates with a sealant; and

injecting a liquid crystal between the first substrate and the second substrate; and

positioning said backlight device beneath said second substrate such that said second substrate is located between said backlight device and said first substrate.

13. (Currently Amended) The method of claim 12, further comprising:

forming a the first light absorbing film between the first substrate and the gate electrode; and

forming a second light absorbing film between the semiconductor active layer and the source and drain electrodes.

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14. (Currently Amended) The method of claim 12, further comprising:

forming a the first light absorbing film between the first substrate and

the gate electrode; and

forming a second light absorbing film between the semiconductor active

layer and the gate insulating layer.

15. (Original) The method of claim 13, wherein the common electrode

and the pixel electrode are made of indium tin oxide.

16. (Original) The method of claim 14, wherein the common electrode

and the pixel electrode are made of indium tin oxide.

17. (Original) The method of claim 13, wherein the common electrode is

made of an opaque conductive material.

18. (Original) The method of claim 14, wherein the common electrode is

made of an opaque conductive material.

19. (Original) The liquid crystal display device of claim 7, wherein the

common electrode and the pixel electrode are made of a transparent material.

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20. (Previously Presented) The method of claim 13, wherein the common electrode and the pixel electrode are made of a transparent material.